

# SANYO Semiconductors DATA SHEET

# 2SK3747 — High-Voltage, High-Speed Switching Applications

#### **Features**

- · Low ON-resistance, low input capacitance, ultrahigh-speed switching.
- · High reliability (Adoption of HVP process).
- · Attachment workability is good by Mica-less package.
- · Avalanche resistance guarantee.

## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		1500	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		2	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	4	Α
Allowable Power Dissipation	Do		3.0	W
	PD	Tc=25°C	50	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		42	mJ
Avalanche Current *2	IAV		2	Α

<sup>\*1</sup> V<sub>DD</sub>=99V, L=20mH, I<sub>AV</sub>=2A

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			- Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	1500			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =1200V, V <sub>GS</sub> =0			100	μΑ
Gate-to-Source Leakage Current	IGSS	VGS= ±16V, VDS=0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	2.5		3.5	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =20V, I <sub>D</sub> =1A	0.7	1.4		S
Static Drain-to-Source On-State Resistance	RDS(on)	ID=1A, VGS=10V		10	13	Ω

Marking: K3747 Continued on next page.

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<sup>\*2</sup> L≤20mH, single pulse

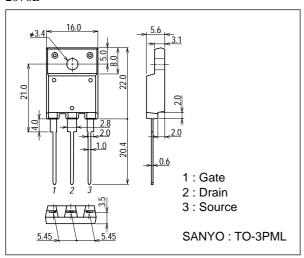
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Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	VDS=20V, f=1MHz		400		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		85		pF
Reverse Transfer Capacitance	Crss	VDS=20V, f=1MHz		45		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		12.5		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		30		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		152		ns
Fall Time	tf	See specified Test Circuit.		45		ns
Total Gate Charge	Qg	V <sub>DS</sub> =200V, V <sub>GS</sub> =10V, I <sub>D</sub> =2A		37.5		nC
Gate-to-Source Charge	Qgs	VDS=200V, VGS=10V, ID=2A		2.7		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =200V, V <sub>GS</sub> =10V, I <sub>D</sub> =2A		20		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =2A, V <sub>GS</sub> =0		0.88	1.2	V

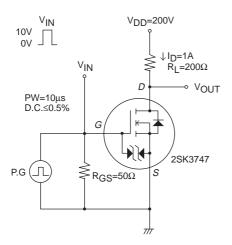
Note) Although the protection diode is contained between gate and source, be careful of handling enough.

## **Package Dimensions**

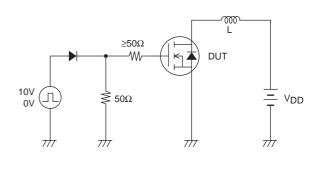
unit : mm 2076B

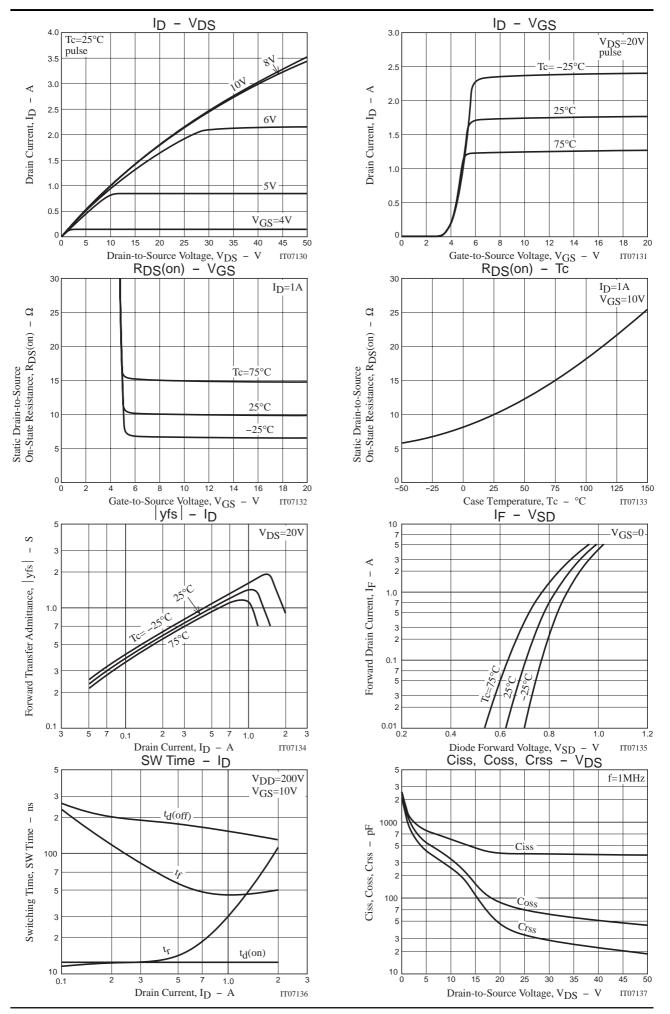


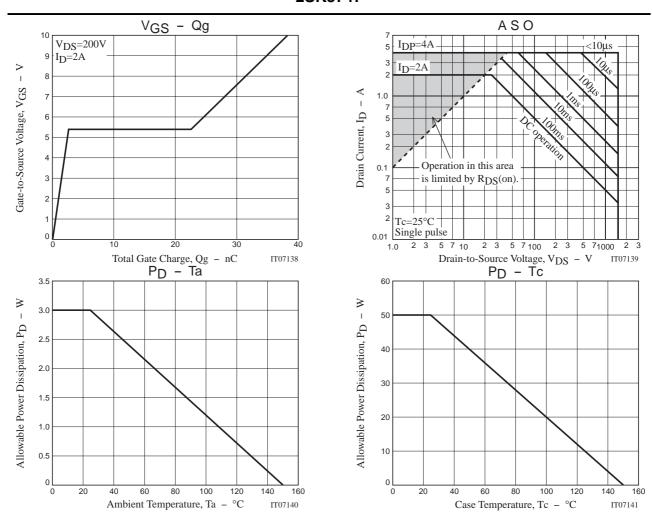
# **Switching Time Test Circuit**



# **Unclamped Inductive Test Circuit**







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